PNP
MJL21195*
NPN
MJL21196*

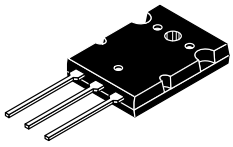
*Motorola Preferred Device

Silicon Power Transistors

The MJL21195 and MJL21196 utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and linear applications.

- Total Harmonic Distortion Characterized
- High DC Current Gain – h_{FE} = 25 Min @ I_C = 8 Adc
- Excellent Gain Linearity
- High SOA: 2.50 A, 80 V, 1 Second

16 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 250 VOLTS 200 WATTS



CASE 340G–02
TO–3PBL

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	250	Vdc
Collector–Base Voltage	V_{CBO}	400	Vdc
Emitter–Base Voltage	V_{EBO}	5	Vdc
Collector–Emitter Voltage – 1.5 V	V_{CEX}	400	Vdc
Collector Current — Continuous Peak (1)	I_C	16 30	Adc
Base Current – Continuous	I_B	5	Adc
Total Power Dissipation @ T_C = 25°C Derate Above 25°C	P_D	200 1.43	Watts W/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	– 65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	0.7	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typical	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage (I_C = 100 mAdc, I_B = 0)	$V_{CEO(sus)}$	250	—	—	Vdc
Collector Cutoff Current (V_{CE} = 200 Vdc, I_B = 0)	I_{CEO}	—	—	100	μAdc

(1) Pulse Test: Pulse Width = 5.0 μs, Duty Cycle ≤10%.

(continued)

Preferred devices are Motorola recommended choices for future use and best overall value.

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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typical	Max	Unit
OFF CHARACTERISTICS						
Emitter Cutoff Current (V_{CE} = 5 Vdc, I_C = 0)		I_{EBO}	—	—	100	μAdc
Collector Cutoff Current (V_{CE} = 250 Vdc, $V_{BE(off)}$ = 1.5 Vdc)		I_{CEX}	—	—	100	μAdc
SECOND BREAKDOWN						
Second Breakdown Collector Current with Base Forward Biased		$I_{S/b}$				Adc
(V_{CE} = 50 Vdc, t = 1 s (non–repetitive)			4.0	—	—	
(V_{CE} = 80 Vdc, t = 1 s (non–repetitive)			2.25	—	—	
ON CHARACTERISTICS						
DC Current Gain		h_{FE}				
(I_C = 8 Adc, V_{CE} = 5 Vdc)			25	—	100	
(I_C = 16 Adc, I_B = 5 Adc)			8	—	—	
Base–Emitter On Voltage (I_C = 8 Adc, V_{CE} = 5 Vdc)		$V_{BE(on)}$	—	—	2.2	Vdc
Collector–Emitter Saturation Voltage		$V_{CE(sat)}$				Vdc
(I_C = 8 Adc, I_B = 0.8 Adc)			—	—	1.4	
(I_C = 16 Adc, I_B = 3.2 Adc)			—	—	4	
DYNAMIC CHARACTERISTICS						
Total Harmonic Distortion at the Output		T_{HD}				%
V_{RMS} = 28.3 V, f = 1 kHz, P_{LOAD} = 100 W_{RMS}	h_{FE} unmatched		—	0.8	—	
(Matched pair h_{FE} = 50 @ 5 A/5 V)	h_{FE} matched		—	0.08	—	
Current Gain Bandwidth Product (I_C = 1 Adc, V_{CE} = 10 Vdc, f_{test} = 1 MHz)		f_T	4	—	—	MHz
Output Capacitance (V_{CB} = 10 Vdc, I_E = 0, f_{test} = 1 MHz)		C_{ob}	—	—	500	pF

(1) Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤2%

PNP MJL21195

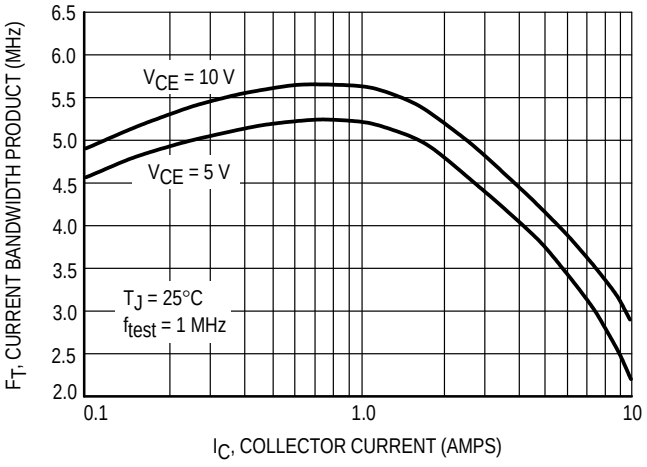

Figure 1. Typical Current Gain Bandwidth Product

NPN MJL21196

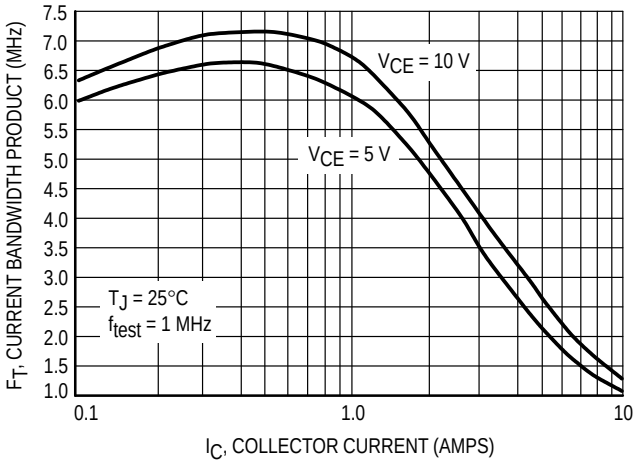

Figure 2. Typical Current Gain Bandwidth Product

TYPICAL CHARACTERISTICS

PNP MJL21195

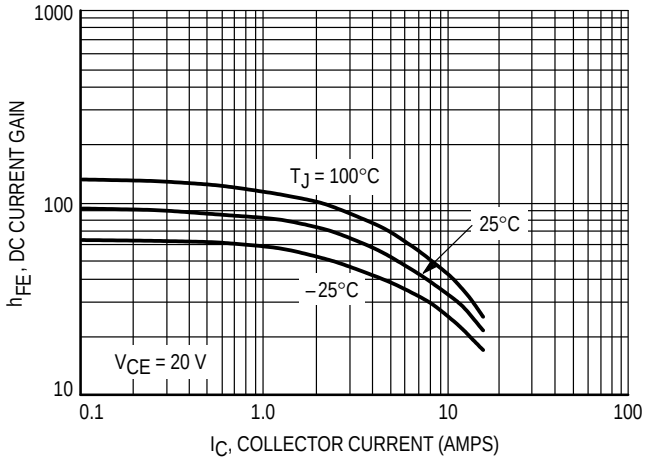

Figure 3. DC Current Gain, V_{CE} = 20 V

NPN MJL21196

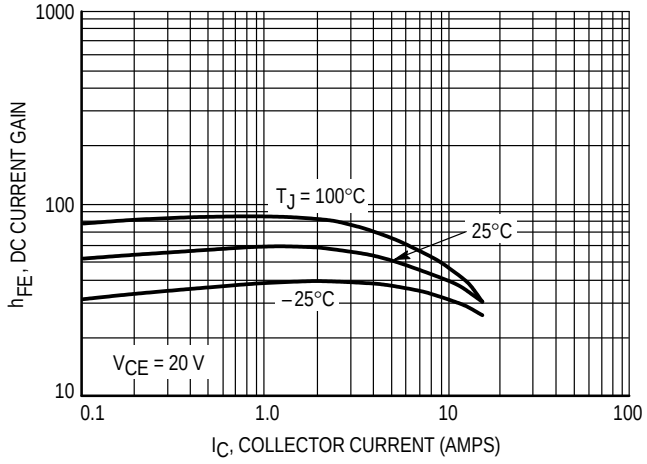

Figure 4. DC Current Gain, V_{CE} = 20 V

PNP MJL21195

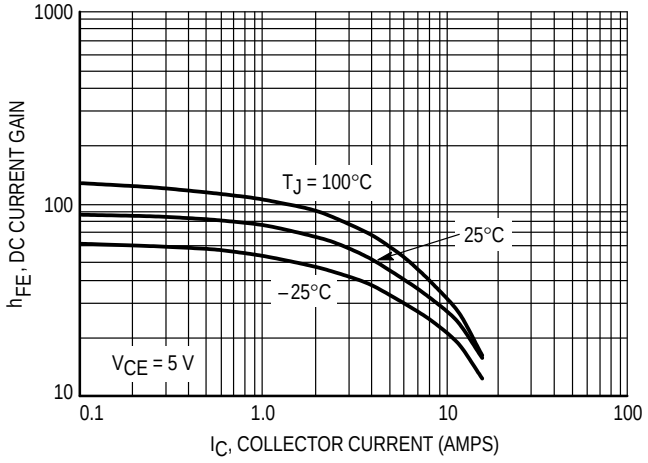

Figure 5. DC Current Gain, V_{CE} = 5 V

NPN MJL21196

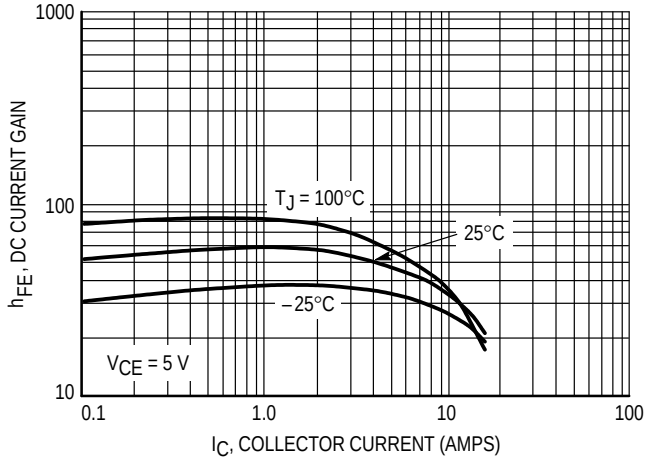

Figure 6. DC Current Gain, V_{CE} = 5 V

PNP MJL21195

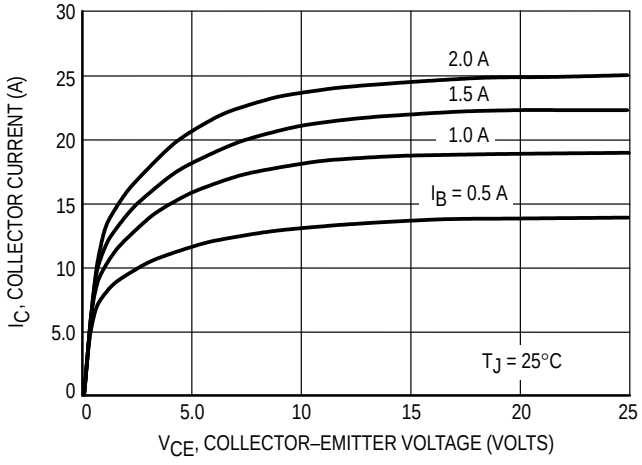

Figure 7. Typical Output Characteristics

NPN MJL21196

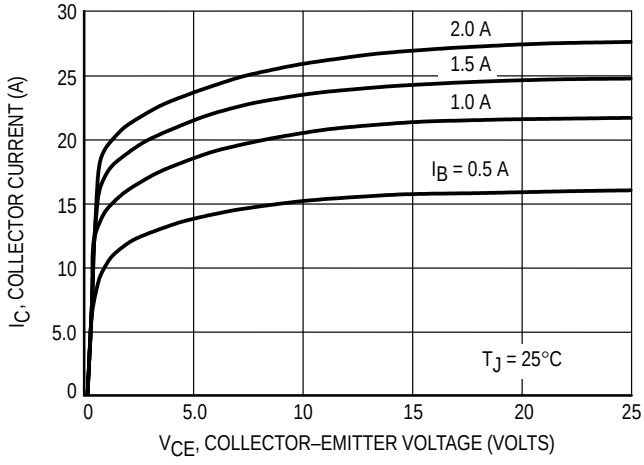

Figure 8. Typical Output Characteristics

TYPICAL CHARACTERISTICS

PNP MJL21195

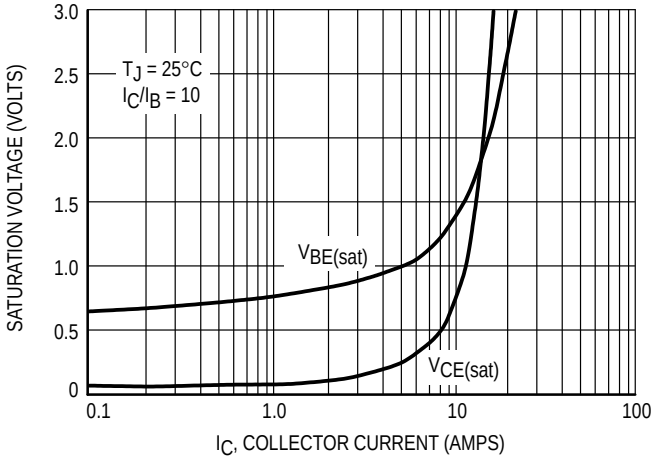

Figure 9. Typical Saturation Voltages

NPN MJL21196

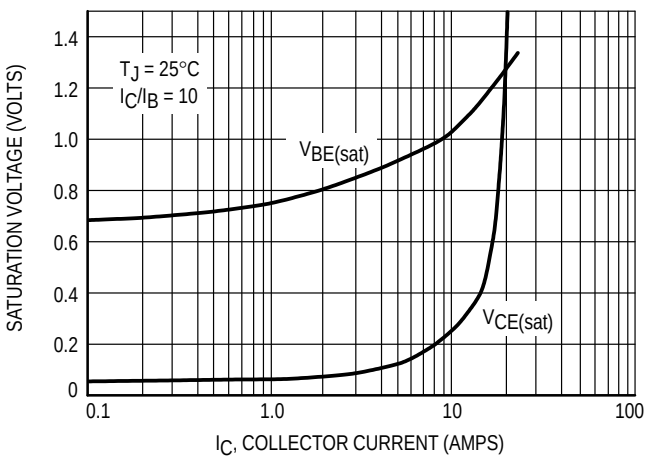

Figure 10. Typical Saturation Voltages

PNP MJL21195

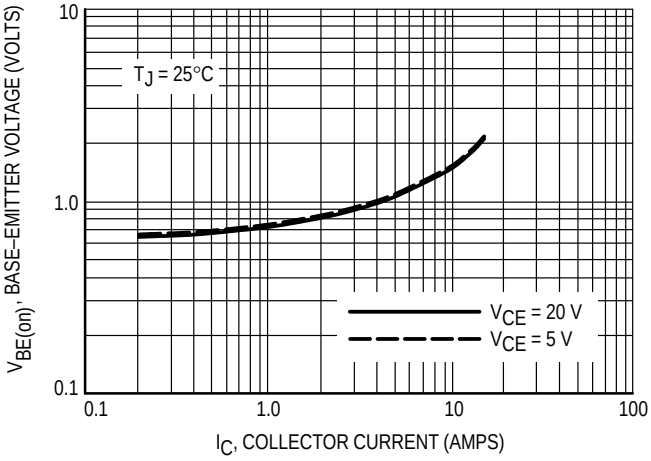

Figure 11. Typical Base–Emitter Voltage

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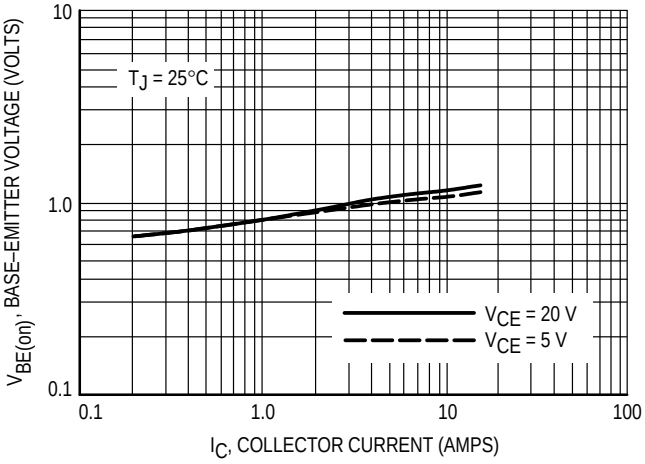


Figure 12. Typical Base–Emitter Voltage

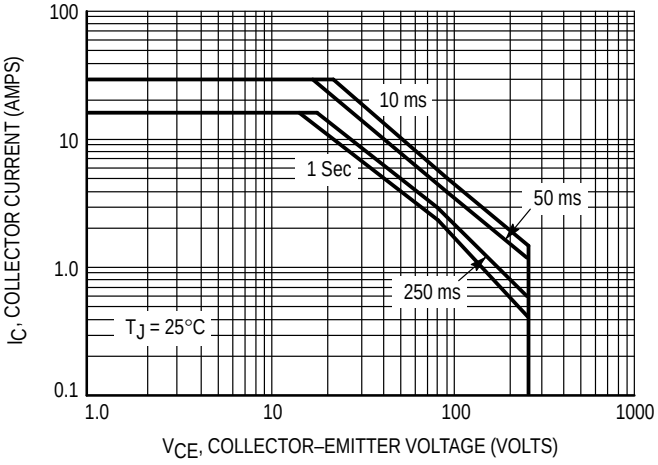


Figure 13. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 13 is based on $T_{J(pk)}$ = 200°C; T_C is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

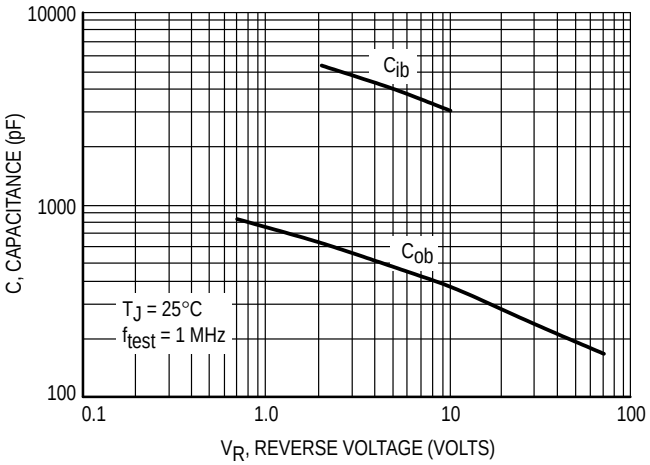


Figure 14. MJL21195 Typical Capacitance

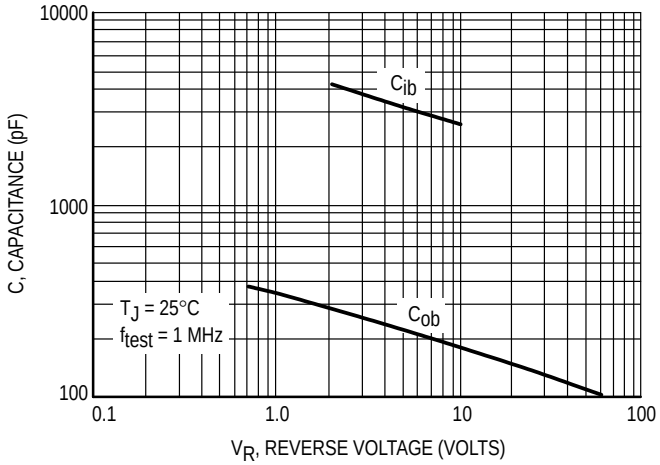


Figure 15. MJL21196 Typical Capacitance

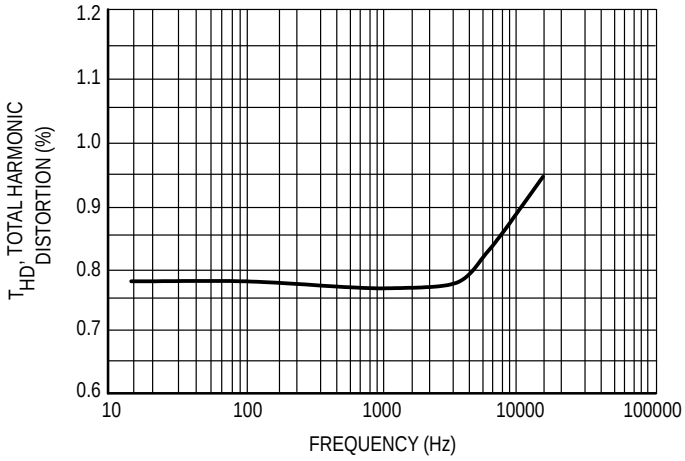


Figure 16. Typical Total Harmonic Distortion

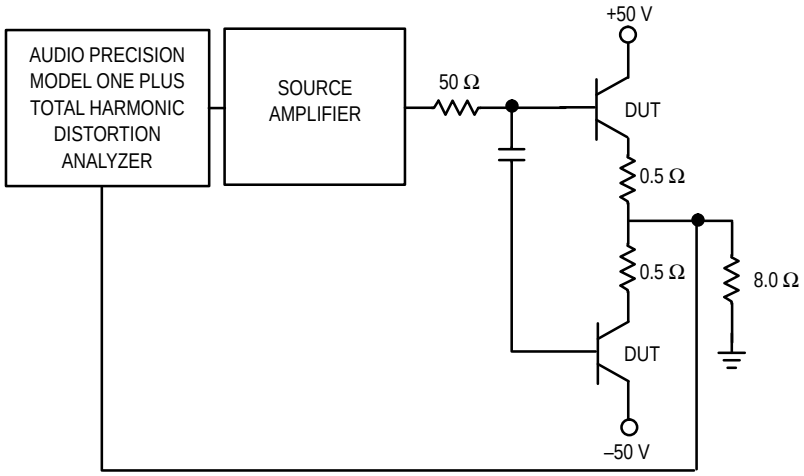
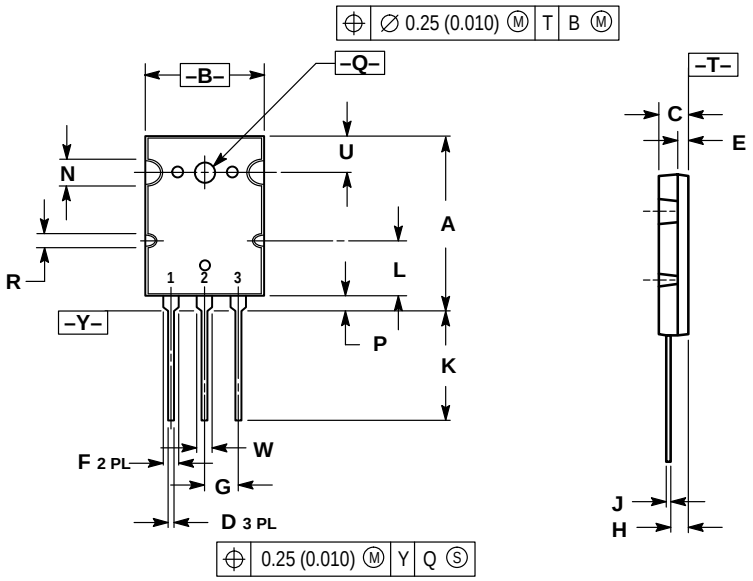


Figure 17. Total Harmonic Distortion Test Circuit

PACKAGE DIMENSIONS



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	2.8	2.9	1.102	1.142
B	19.3	20.3	0.760	0.800
C	4.7	5.3	0.185	0.209
D	0.93	1.48	0.037	0.058
E	1.9	2.1	0.075	0.083
F	2.2	2.4	0.087	0.102
G	5.45 BSC		0.215 BSC	
H	2.6	3.0	0.102	0.118
J	0.43	0.78	0.017	0.031
K	17.6	18.8	0.693	0.740
L	11.0	11.4	0.433	0.449
N	3.95	4.75	0.156	0.187
P	2.2	2.6	0.087	0.102
Q	3.1	3.5	0.122	0.137
R	2.15	2.35	0.085	0.093
U	6.1	6.5	0.240	0.256
W	2.8	3.2	0.110	0.125

STYLE 2:
PIN 1. BASE
2. COLLECTOR
3. EMITTER

CASE 340G–02
TO–3PBL
ISSUE F

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